Effects of Al and N plasma immersion ion implantation on surface microhardness, oxidation resistance and antibacterial characteristics of Cu

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Abstract: Al and N were introduced into copper substrate using plasma immersion ion implantation (PIII) in order to enhance its hardness and oxidation resistance. The dosage of N ion is $5\times10^{16}$ cm$^{-2}$, and range of dosage of Al ion is $5\times10^{16}$ to $2\times10^{17}$ cm$^{-2}$. The oxidation tests indicate that the copper samples after undergoing PIII possess higher oxidation resistance. The degree of oxidation resistance is found to vary with implantation dosage of Al ion. The antibacterial tests also reveal that the plasma implanted copper specimens have excellent antibacterial resistance against *Staphylococcus aureus*, which are similar to pure copper.

Key words: copper; plasma immersion ion implantation; nanoindentation; oxidation resistance; antibacterial properties

1 Introduction

Besides the application in microelectronic packaging [1], copper has been used as an excellent antibacterial agent for many years [2–4], for its high bactericidal rate to many bacteria such as *Staphylococcus aureus* [5] and *Escherichia coli* [6,7]. Compared with organic antibacterial agents, metal copper has desirable properties such as good machinability, stability, relative non-toxicity, and broad spectrum antibiosis boasting high antibacterial activity against both bacteria and fungi. However, copper still has suffered some disadvantages such as low hardness compared with other metals such as stainless steels and vulnerable to oxidation, thereby limiting its applications. It is known that the surface performances of copper can affect its antibacterial properties as well as appearance. Therefore, it is significant to improve the surface hardness and enhance the oxidation resistance of copper while not compromising its other desirable properties.

The mechanical properties of copper can be improved by electrodeposition [8–10] and its oxidation resistance has been enhanced by means of electroless deposition [11], chemical vapor deposition [12], and other methods [13,14]. Among the surface modification techniques, ion implantation is an effective method to modify the mechanical and chemical properties such as hardness, wear, fatigue, friction, and oxidation resistance, of metal and non-metal materials [15–17]. The improved mechanical properties can usually be attributed to radiation-enhanced diffusion, ion-induced chemical reactions, grain refinement, and defect generation. Recently, plasma immersion ion implantation (PIII) has attracted much attention as this technique offers unique advantages including the possibility to treat large industrial components with complex shape without extensive sample manipulation as well as high dose rate and large area capabilities [18]. Up to now, most of the existing literature about Cu ion implantation has focused on materials modified by Cu ion implantation [19–21], but the literature on enhancing properties of copper by ion implantation is seldom [22].

In this work, copper samples were implanted sequentially with aluminum and nitrogen at lower negative bias and different Al implantation dosages. Our results disclose that the implanted copper specimens have not only higher hardness, but also better oxidation...
Resistance. The PIII-treated copper samples show good antibacterial performance: they have an almost 100% bactericidal rate against *Staphylococcus aureus*, which is similar to that observed on pure copper. The lower negative bias employed in the PIII process and low cost enable commercialization of the experimental protocols described in this work.

## 2 Experimental

### 2.1 Sample preparation

Copper samples were mechanically polished and cleaned before undergoing PIII. Al and N were implanted into the copper samples successively using a PIII instrument equipped with Al cathodic arc source and nitrogen gas plasma sustained by radio frequency (RF) excitation. The detailed preparation procedures can be found in Ref. [23]. In this work, Samples S1, S2, S3, S4, S5 and S6 were subjected to different treatments and the treatment parameters are summarized in Table 1.

### 2.2 Characterization of mechanical properties and oxidation resistance

The mechanical properties of Samples S1, S2 and S3 were determined using continuous stiffness measurements by nanoindentation on the MTS Nano Indenter (XP) system. The nanoindentation tests were conducted in air at room temperature, and each sample was measured three times at different locations to obtain the corresponding mean values. X-ray photoelectron spectroscopy (XPS, physical electronics PHI−5802) was employed to determine the depth profiles and valence states of oxygen and copper in Samples S4, S5 and S6. A sputtering rate of 25.9 nm/min was used for Sample S4 and a sputtering rate of 1.84 nm/min was used for Samples S5 and S6.

### 2.3 Antibacterial activities

*Staphylococcus aureus* ATCC6538 (*S. aureus*, Gram-positive) was used to evaluate the antibacterial properties of Samples S1, S2 and S3 by the plate-counting method in which pure copper was used as the positive control and the culture dish was used as the negative control. To guarantee the accuracy of measuring values, each group contains three parallel samples. Before the antibacterial test, the samples were sterilized with 75% ethanol overnight and air dried. Then, 0.1 mL solution of bacteria (2×10⁵−5×10⁶ CFU/mL) was added onto the surface of each sample and covered by a polyethylene (PE) film (15 mm×15 mm). The bacteria were subsequently added onto the samples which were incubated at 37 °C and about 90% humidity for 24 h. Afterwards, they were thoroughly washed with a sterile phosphate-buffered saline (PBS) solution that contained 0.1% Tween 80 with pH 7.2−7.4. To observe the living bacteria, 1, 0.1 and 0.01 mL of the washing solutions were added to different dishes containing the nutrient agar. After 24 h of incubation under similar conditions, the subsequent macroscopic bacterial colonies were counted and the antibacterial effect was quantitatively determined using the following equation [24]:

\[
R = \frac{B - C}{B} \times 100\%
\]

where *R*, *B* and *C* are the antibacterial effect, the mean number of bacteria on the control samples (CFU/sample), and the mean number of bacteria on the modified samples, respectively.

## 3 Results and discussion

### 3.1 Mechanical properties

Figure 1 depicts the load versus depth curves and hardness versus depth curves of Samples S1, S2 and S3. It can be seen from Fig. 1(a) that a higher load is needed to penetrate the same depth for Samples S2 and S3 compared with Sample S1, and so the plasma implanted samples have higher hardness as shown in Fig. 1(b). The higher hardness of Samples S2 and S3 may be attributed to lattice distortion resulting from irradiation damage and defects including cavities and interstitial atoms. It can be seen from Fig. 1(b) that the maximum hardness of Sample S3 at the depth of 7−8 nm is about 3 times that of Sample S1, whereas the maximum hardness of Sample S2 is about twice that of Sample S1. One possible explanation is that the larger Al implantation dosages result in higher radiation damage and more defects.

### 3.2 Oxidation behavior

Figure 2 displays the changes in the oxidation
behavior of the implanted samples after being exposed to air at 260 °C for 1 h. Comparing the elemental distributions of Samples S5 and S6 with that of Sample S4, the penetration of oxygen in Samples S5 and S6 is much smaller. In Sample S4, oxygen extends to a depth of 240–275 nm. In comparison, in Samples S5 and S6, oxygen can only be found up to depths of 45 and 35 nm, respectively. The oxygen depth in Sample S6 is only about 1/9 of that in Sample S4, and the maximum depth of oxygen in Sample S6 is smaller than that in Sample S5. It may be attributed to different Al implantation dosages [23].

The Cu 2p XPS spectra of Samples S4, S5, and S6 are depicted in Fig. 3 and the possible Cu phases are listed in Table 2. It can be observed that copper mainly exists in the form of CuO (binding energies of 933.6 and 953.6 eV) on the surface and near the surface of Sample S4. The CuO peak is dominant up to a depth of about 26 nm and as expected, the content of CuO decreases with increasing depth in Sample S4. In contrast, elemental copper (binding energies of 932.2 and 952.0 eV) is the main form near the surface of Samples S5 and S6 except for trace Cu₂O, and almost all of copper exists in the form of elemental copper when the depth is 3.68 nm. The results indicate that copper samples are effectively protected from surface oxidation by Al implantation.

Figure 3 and Table 2 show that the Cu 2p peaks at 0 and 1.84 nm in Samples S5 and S6 are very weak and the main reason may be that the introduction of Al to the near surface region in Samples S5 and S6 lowers the relative content of copper. By comparing Samples S5 and
Fig. 3 Cu 2p core level binding energy spectra of Samples S4 (a, b, c), S5 (d, e, f), and S6 (g, h, i): (a, d, g) Depth of 0 nm; (b) Depth of 25.91 nm; (c) Depth of 51.82 nm; (e, h) Depth of 1.84 nm; (f, i) Depth of 3.68 nm

Table 2 Possible Cu phases in outermost and near surface of Samples S4, S5 and S6

<table>
<thead>
<tr>
<th>Sample No.</th>
<th>Depth/nm</th>
<th>Existing form of copper</th>
<th>Peak intensity</th>
</tr>
</thead>
<tbody>
<tr>
<td>S4</td>
<td>25.91</td>
<td>▲</td>
<td>▲ Strong</td>
</tr>
<tr>
<td></td>
<td>51.82</td>
<td>▲</td>
<td>▲ (s) Strong</td>
</tr>
<tr>
<td>S5</td>
<td>1.84</td>
<td>△</td>
<td>△ (w) (s)</td>
</tr>
<tr>
<td></td>
<td>3.68</td>
<td>△</td>
<td>△ (w) (s)</td>
</tr>
<tr>
<td>S6</td>
<td>1.84</td>
<td>△</td>
<td>△ (w) (s)</td>
</tr>
<tr>
<td></td>
<td>3.68</td>
<td>△</td>
<td>△ (w) (s)</td>
</tr>
</tbody>
</table>

▲, △ and ○ represent CuO, Cu2O and Cu, respectively; w, m and s represent intensity degree of peak: weak, middle and strong, respectively

S6 (Fig. 3), it can be found that higher content of Cu2O exists in the outermost layer of Sample S5 than that in the outermost layer of Sample S6. The results suggest that different Al implantation fluencies affect the oxidation resistance of copper to some degree.

3.3 Antibacterial activity

The bacteria, *Staphylococcus aureus*, are used to assess the antibacterial activity of pure copper and plasma implanted copper specimens. After culturing for 24 h, an antibacterial rate of almost 100% is observed from both the pure and implanted Cu samples subjected to $2 \times 10^5 - 5 \times 10^5$ CFU/mL *Staphylococcus aureus*. The results acquired from Samples S1, S2 and S3 are summarized in Table 3, which illustrates that Al-PIII and...
N-PIII have no effect on the antibacterial properties of copper, especially for *Staphylococcus aureus*. In comparison, the antibacterial rate observed from the negative control is 0.

The plasma treated copper samples possess both higher surface microhardness and enhanced oxidation resistance while maintaining their high antibacterial activity. Al implanted Cu offers higher oxidation resistance due to the protective Al implanted layer and it is shown in our experiments that this modified layer does not degrade the antibacterial rate.

There are two possible reasons. Firstly, copper is an excellent antibacterial agent, especially to *Staphylococcus aureus* and *Escherichia coli*. A low content copper on the surface of other materials can indeed provide high antibacterial rates against the two types of bacteria. According to the study of ZHANG et al [24], a content of about 3% copper (mass fraction) in the near surface of Cu plasma implanted polyethylene can produce an antibacterial rate of 86.1% against *Staphylococcus aureus*. As shown in Fig. 5 in Ref. [23], the content of copper in the outermost surface on the plasma implanted specimens is about 20% and the Cu content increases with the increase of the depth. Thus, there is an excess supply of Cu from the substrate during the prolonged exposure, thereby rendering the materials with excellent antibacterial properties. Secondly, the surface Al implanted layer has a thickness of about tens of nanometers. When pure Cu undergoes natural oxidation, oxygen penetrates the surface oxide readily, causing continuous oxidation. On the contrary, in the Al implanted Cu samples, most of the incoming oxygen atoms are captured by Al on the near surface due to high chemical affinity between O and Al. Oxygen is thus trapped to form aluminum oxide which impedes further diffusion of oxygen to the bulk of the materials. At the same time, copper atoms from the bulk can diffuse to the surface because the binding force between Cu and Al is much lower than that between O and Al. Consequently, there are enough copper ions on the surface of the Al plasma implanted Cu samples to provide the excellent antibacterial capability.

### 4 Conclusions

1) Surface hardness of copper can be enhanced by Al and N plasma immersion ion implantation, and its values will increase with larger Al implantation dosages during a certain range. The higher surface hardness determined from the plasma treated copper samples stems from lattice distortion resulting from irradiation damage and defects such as cavities and interstitial atoms introduced by PIII.

2) Al and N plasma immersion ion implantation can improve the oxidation resistance of pure copper. The oxidation tests and XPS analysis results also show that the degree of oxidation resistance depends on the Al implantation dosages.

3) PIII-treated copper samples with different Al dosages show excellent antibacterial properties arising from the synergistic effect that copper provides a high antibacterial rate against *Staphylococcus aureus*. Simultaneously, Al atoms on the near surface of copper provide resistance to oxidation of the copper substrate.

### References


Al和N等离子浸没注入对铜表面硬度、氧化和抗菌性能的影响

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摘 要：采用等离子浸没注入方法(PIII)将Al和N注入铜基体中，以提高铜的硬度和抗氧化性能。其中氮离子注入剂量为5×1016 cm−2，铝离子注入剂量范围为5×1016~2×1017 cm−2。氧化实验表明，铜的抗氧化性能随铝离子注入剂量变化；抗菌实验结果表明，对于金黄色葡萄球菌，等离子浸没注入的铜样品具有与纯铜同样优异的抗菌抑菌性能。

关键词：铜；等离子浸没注入；纳米压入；抗氧化；抗菌性能

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